



YJQ018G10AHQ

N-Channel Enhancement Mode Field Effect Transistor

Product Summary

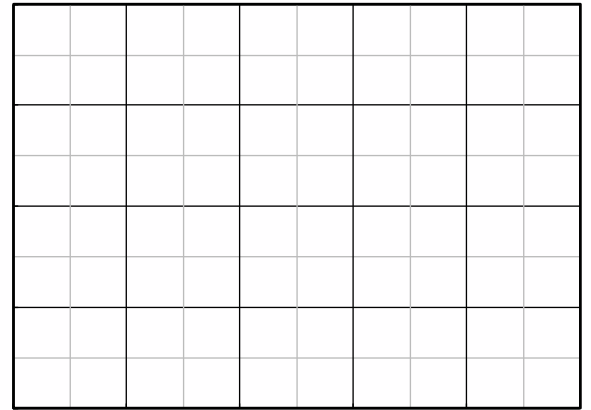
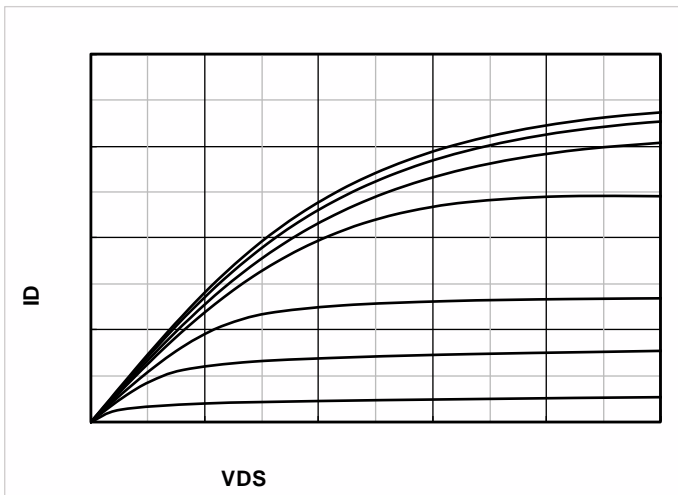
General Description

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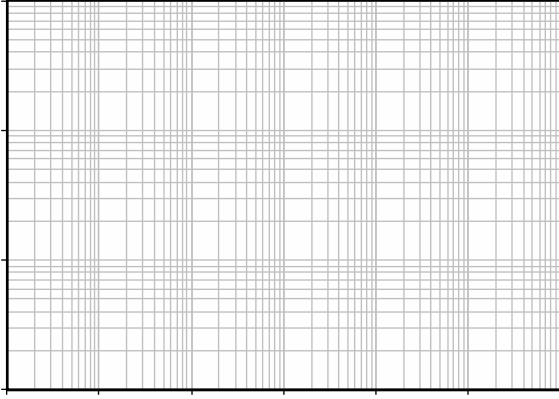
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Typical Electrical and Thermal Characteristics Diagrams



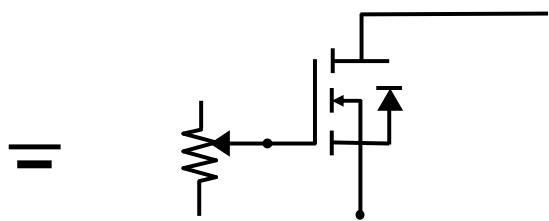


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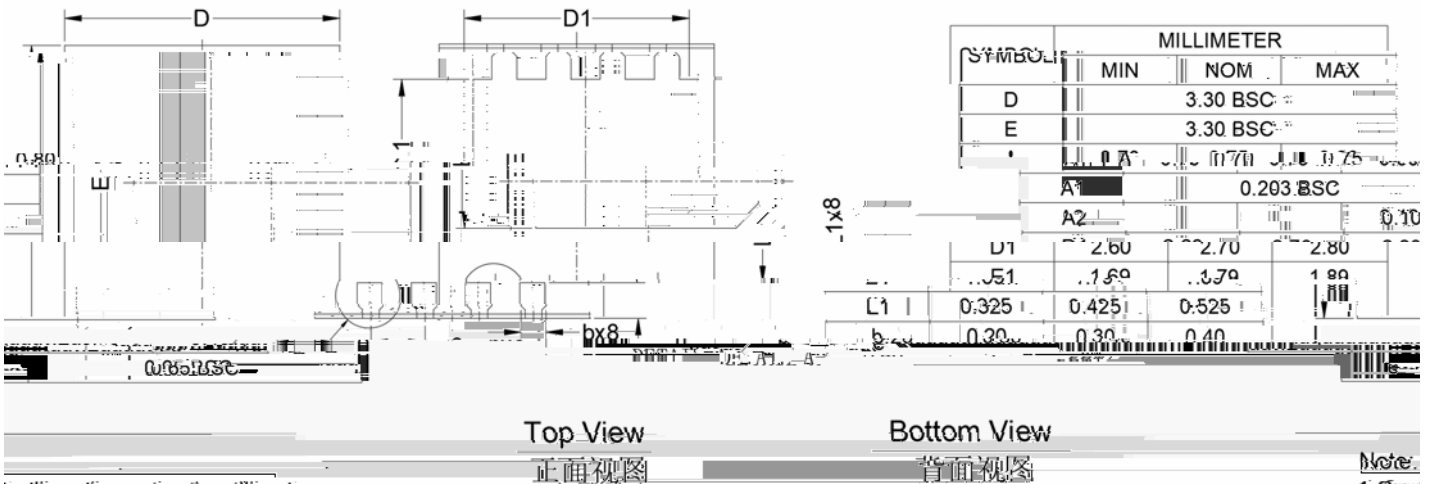
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DFN3333-8L-WF Package information

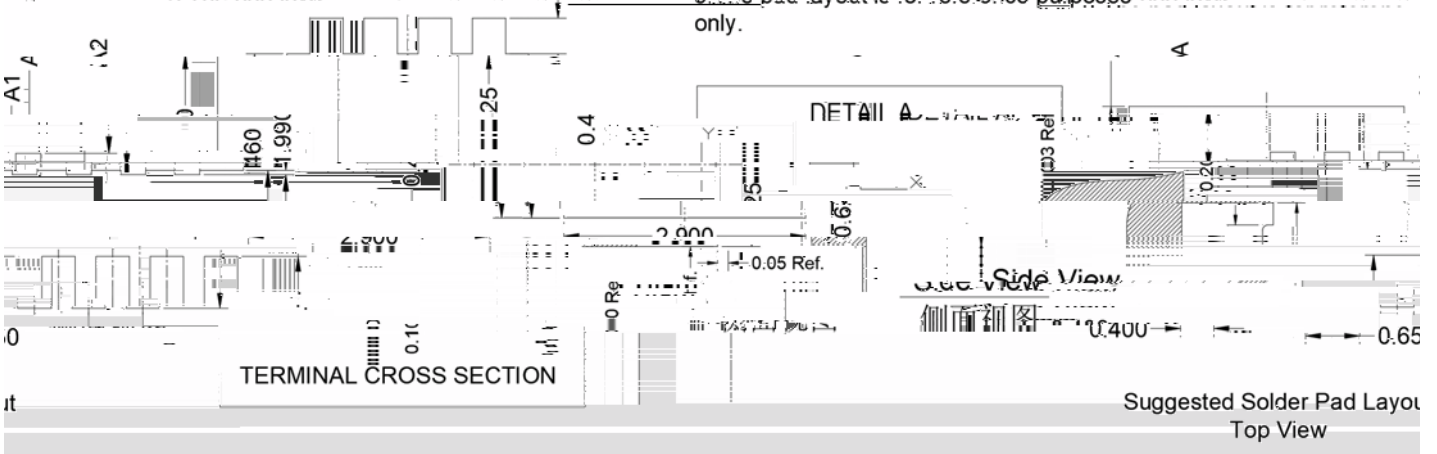


Dimension in millimeters.

Note:
1. Con

2. General tolerance: ±0.10mm.

3. The pad layout is for reference purposes.





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Disclaimer
